Monolithically Integrated Selectable Repetition-Rate Laser Diode Source of Picosecond Optical Pulses

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We describe the characterization of a monolithically integrated photonic device for short pulse generation featuring a mode-locked laser diode, a Mach Zehnder modulator, and a semiconductor optical amplifier (SOA). The integrated device is designed for fabrication by a generic foundry scheme with a view to ease of design, testing and manufacture. Trains of 6.8 ps pulses are generated at repetition rates which are electronically switchable from 14 GHz to 109 MHz. The SOA boosts the peak power by 7.4 dB, and the pulses are compressible to 2.4 ps by dispersion compensation using single-mode telecommunications fibre. © 2013 Optical Society of America

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Ultrafast optical pulse sources have undergone extensive research and commercial development, having found many applications in fields as diverse as optical communications [1], high speed sampling [2], clock distribution [3], and fiber radio [4]. While traditional solid-state and fibre-based sources are generally capable of the highest performance, monolithically mode-locked laser diodes (MMLLDs) are potentially a commercially attractive alternative owing to their properties which include low cost, small footprint, direct electrical pumping, and high wallplug efficiency. While being promising sources in these respects, they have largely been unable to achieve the performance required for the applications described above, in general having low peak powers, long, highly chirped pulses, and high repetition rates. In order for MMLLDs to compete with established solid-state and fibre laser systems it is necessary to improve the performance of currently available devices.

The high repetition rates of most MMLLDs are caused by their inherently short cavities, and the low peak powers are due both to the high repetition rates, and to the low driving currents required for stable mode-locked operation [5]. The repetition rate issue has been addressed monolithically, for example by Cheung et al. [6] who have demonstrated the emission of 36 ps pulses at 1 GHz from a 41 mm long device, and Li et al. [7] who have demonstrated passive modelocking at a fundamental repetition rate of 2.1 GHz in a 20 mm long monolithic two-section quantum dot laser. The peak powers and repetition rates of these low repetition rate lasers are ultimately limited by the effects of large material losses, nanosecond gain recovery times, and high dispersion, all of which become more problematic as cavity lengths increase. Increased peak powers however can be achieved by using monolithic master oscillator power amplifier (MOPA) configurations. Olle et al. [8] have demonstrated 10 ps Fourier transform limited pulses with peak powers exceeding 0.31 W at a 20.4 GHz repetition rate. Faugeron et al. [9] have reported 10 GHz subpicosecond pulses with 18 W peak power from an asymmetrical cladding single-section quantum-dash mode-locked laser. Ahmad et al. [10] also reported fundamental (~ 5.2 GHz) and subharmonic hybrid modelocking of a high power (220 mW) monolithic semiconductor laser.

At present, although photonic integrated circuits (PIC) have shown promise as a transformative technology, their widespread adoption has been hindered by the prohibitive cost of designing bespoke components and accessing foundry facilities. One proposed solution would be for...
PICs to take a similar development path to that followed by microelectronic integration technology [14], that is, to provide a basic set of standardized components using generic from which more complex circuits can be built. Recently however InP generic foundries have used a selection of basic optoelectronic components to assemble Application Specific Photonic Integrated Circuits (ASPICs) [15], in our work therefore, particularly given our need for repeated device optimization, this generic foundry design and fabrication scheme is used.

In this paper we present a novel scheme where a MLLD, Mach-Zehnder Modulator (MZM) and SOA are monolithically integrated using an InP foundry. The MLLD is used to generate a stable high repetition rate train of low peak power pulses which is then modulated by the MZM, thus decreasing the repetition rate of the pulse train and providing repetition rate flexibility. Finally, the SOA boosts the power particularly of the low repetition rate pulse train, thus resulting in a more efficient conversion of average power to peak power.

As well as improved peak powers and variable repetition rates, a further advantage of this design is that it enables a single device to output pulse trains covering a very wide parameter space, allowing the device to be optimized electronically to suit the performance requirements of a given application. This is a particularly advantageous feature for applications where optimization of the source can yield significant improvements in the system performance, such as in multi-photon imaging [16], optical coherence tomography [17], and optical sampling [18].

![Diagram of the drive electronics used for hybrid modelocking](https://via.placeholder.com/150)

Fig. 1. A microscope image of the integrated device and a schematic diagram of the drive electronics used for hybrid modelocking, modulation and amplification of the pulse train.

Fig. 1 shows a microscope image of the device and a schematic of the associated experimental electronics. The indium phosphide based multi quantum-well device studied in this work is fabricated using a photonic integrated circuit generic foundry approach [14]. The laser cavity consists of an HR coating on one facet, four 50 µm long absorbers, a 2.1 mm long gain section, and 0.57 mm of passive waveguide with a DBR section as an output coupler. The DBR has a coupling strength of 50 cm⁻¹, and a length of 50 µm. The four pads of the saturable absorber can be independently electrically connected, allowing the length of the absorber to be varied to optimize the laser performance. An absorber length of 100 µm is used throughout this work. The total laser cavity length is 3.0 mm resulting in a fundamental repetition rate of 14 GHz. Hybrid modelocking is achieved with the gain section driven by a DC current and the absorber section driven by a reverse DC voltage plus RF modulation. The device is mounted on a copper heatsink whose temperature is maintained at 20 °C, leading to a lasing wavelength of 1540 nm.

The pulse train emitted by the laser is split by a 1×2 MMI coupler into the Mach-Zehnder modulator. Each arm of the MZM contains one 1090 µm long electro-optic phase modulator. The modulator in one arm of the MZM is driven via a bias tee with the DC + RF voltage required for inducing a phase shift alternating between 0 and π or 2π so as to alternately cause constructive or destructive interference with the other arm, and therefore to modulate the signal emitted from the MZM as a whole. The reduced repetition rate pulse trains are directed either to a passive waveguide output channel, or to an output waveguide containing a 750 µm long SOA. Both outputs are AR coated and angled at 7 degrees to minimize feedback. Pulses from either output are collected by a lensed fiber for transmission to the diagnostic instruments. The external RF signal sources for hybrid modelocking and MZM modulation are synchronized through a common 10 MHz clock. A programmable pattern generator is then used to generate the desired drive waveform to achieve a specific repetition rate. By applying a waveform of variable frequency and duty cycle to one arm of the MZM, the 14 GHz pulse train from the MLLD is then modulated and variable repetition rates can be generated. Finally, the power of the modified repetition rate pulse trains is amplified by the SOA section which is driven by a DC current.

The stable mode-locking regime lies in the gain section current range of 160-190 mA and absorber section reverse bias voltage of 1.7-2.1 V. Optimal hybrid modelocking is demonstrated by applying a 180 mA DC current to the gain section (2.4 times higher than the threshold current) and -2.04 V DC bias voltage with RF modulation to the saturable absorber section via a bias tee. The RF modulation frequency is chosen to be close to the fundamental repetition rate of 13.94 GHz.

![Optical spectrum and RF spectrum](https://via.placeholder.com/150)

Fig. 2 and Fig. 3 show the optical spectrum, RF spectrum and autocorrelations of a typical pulse train. The measured spectral bandwidth in this case is 2.54 nm and the pulse duration 7.8 ps assuming a sech² pulse.
profile, so that the pulse is 8 times transform limited, and hence is strongly chirped. The chirp may result from the changes in refractive index caused by the change of carrier density in the absorber and the gain sections, and also from waveguide dispersion.

Modulation of the pulse train has been achieved by applying square wave modulation signals between 4.3 V and 2.3 V at the desired frequency and duty cycle to one arm of the MZM. Extra peaks occur in the RF spectra corresponding to the modulation frequencies. Fig. 5 shows oscilloscope traces of an unmodulated 14 GHz pulse train and the same pulse train modulated to a decreased repetition rate of 109 MHz measured via the passive waveguide output. The inset of Fig. 5 (b) shows that two pulses are transmitted by the MZM rather than a single pulse. This is because the bandwidth of the pattern generator (12.5 GHz) is lower than the 14 GHz fundamental repetition rate of the laser. A higher bandwidth pattern generator would allow single pulse picking.

Pulses with shorter durations are achieved by dispersion compensation of the laser output which further increases the peak power while maintaining the pulse quality. For the optimal pulse compression and under similar driving conditions to those above, the investigated pulse is chosen with a spectral width of 1.76 nm and initial pulse duration of 8.7 ps. The time-bandwidth product of 1.93 is 6.1 times larger than the transform limited value of 0.315 for sech^2 pulses.

Different lengths of standard SMF-28 fibre, with a group velocity dispersion of 16 ps/km/nm at 1550 nm, have been used to compensate for the linear component of the dispersion. The length of the single-mode fiber is optimized for shortest pulse width, and the autocorrelation traces measured after various lengths of the SMF-28 are shown in Fig. 4. The shortest dispersion compensated pulse, 2.4 ps in duration, has been achieved with a fibre length of 315 m, corresponding to a total dispersion of 5.0 ps/nm. The reduction in pulse duration corresponds to a reduction from 6.1 to 1.7 times transform limited. A small pedestal can be seen in the autocorrelation of this pulse, which is indicative of the presence of high-order dispersion which is not compensated for in the SMF-28 fiber, but could be compensated with more complex experimental approaches such as grating pairs [19], but clearly the majority of energy is in the main pulse.

![Fig. 3. Colinear autocorrelations of the pulse train emitted by the hybrid mode-locked MLLD, showing (a) a train of peaks of equal heights, and (b) a sech-squared fit to the zero delay peak corresponding to a pulse duration of 7.8 ps.](image)

![Fig. 4. Colinear autocorrelation traces after dispersion compensation in different lengths of SMF-28 fiber. The shortest measured pulse width is 2.4 ps at a fibre length of 325 m.](image)

![Fig. 5. Sampling oscilloscope traces of (a) an unmodulated pulse train at a repetition rate of 14 GHz (200 ps/div), (b) a modulated pulse train at 109 MHz (1 ns/div).](image)
that of the pulse without modulation and amplification, which may be due to dispersion compensation by the small positive dispersion introduced in the phase modulators. While autocorrelations of the unmodulated pulse train show a sequence of equal-height pulses, the three dominant peaks of unequal heights in Fig. 6 (a) are consistent with the autocorrelation of a pair of isolated pulses rather than a continuous pulse train. The small peak after the three dominant peaks is due to the imperfect extinction ratio in the MZM, and could be reduced by improved fabrication.

Fig. 6. Collinear autocorrelations of a modulated and amplified pulse train. (a) group of peaks and (b) zero delay peak.

The measured output parameters for (1) pure hybrid modelocking and (2) hybrid modelocking plus modulation to a repetition rate of 109 MHz and SOA amplification at a current of 31 mA, are compared in Table 1.

<table>
<thead>
<tr>
<th>Pulse performance</th>
<th>(1)</th>
<th>(2)</th>
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<tbody>
<tr>
<td>Spectra width (nm)</td>
<td>2.54</td>
<td>2.11</td>
</tr>
<tr>
<td>Pulse width (ps)</td>
<td>7.78</td>
<td>6.81</td>
</tr>
<tr>
<td>Time bandwidth product</td>
<td>2.50</td>
<td>1.82</td>
</tr>
<tr>
<td>Max. pulse energy (pJ)</td>
<td>0.10</td>
<td>0.41</td>
</tr>
<tr>
<td>Fiber coupled average power (mW)</td>
<td>1.20</td>
<td>0.45</td>
</tr>
<tr>
<td>Max. peak power (mW)</td>
<td>9.57</td>
<td>53</td>
</tr>
<tr>
<td>Min. rep rate (GHz)</td>
<td>14</td>
<td>0.11</td>
</tr>
</tbody>
</table>

In summary, a monolithically integrated short pulse source consisting of an MLLD, a MZM and a MOPA is demonstrated. The MZM and MOPA expand the functionality of the device beyond that of the MLLD alone, enabling increased peak powers and tunable repetition rates. The design and fabrication are achieved using a generic foundry scheme. 6.8 ps pulses are generated at repetition rates which can be switched electronically from 14 GHz to 109 MHz. Pulse compression to a duration of 2.4 ps in SMF-28 fibre is also demonstrated, increasing the peak power by a factor of three. Also, even with a low current applied to the SOA, the pulse peak power is increased by 7.4 dB without major degradation of any of the pulse parameters. This proof-of-principle device has shown the interplay of pulse picking and amplification. The use of pulse picking to enable boosted peak powers after amplification makes possible performance levels which are approaching those that would be suitable for biophotonic applications, despite using a compact and cost effective platform.

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Reference